NSN 5961-01-482-0917

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-482-0917 **Inclosure Material:** Glass **Overall Length:** Between 0.130 inches and 0.146 inches **Overall Diameter:** Between 0.063 inches and 0.067 inches **End Application:** Electronic component assembly **Electrode Internally-electrically Connected To Case:** Cathode **Criticality Code Justification:** Voltage Rating In Volts Per Characteristic: 12.0 regulator voltage **Voltage Tolerance In Percent:** -5.0/+5.0 **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Surface mount avalanche diode; hermatically sealed glass casing; tin-lead plated solderable end caps; internal mettalurgical bonding Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: